

## PRODUCT DESCRIPTION

The AD8541ARZ-REEL7(single), AD8542ARZ-REEL7(dual) and AD8544ARZ-REEL7(quad) are low voltage micro power CMOS voltage feedback operational amplifiers. With an excellent bandwidth of 1.

3MHz, a slew rate of 0.9V/µs, and a quiescent current of 70µA per amplifier at 5V, the AD854xARZ-REEL7 family can be designed into a wide range of applications.

The AD854xARZ-REEL7 op-amps are specifically designed for general-purpose applications with optimal performance. They have a wide input commonmode voltage range and excellent output voltage swingsand the maximum input offset voltage are 2.5mV. These parts provide rail-to-rail output swing into heavy loads. The AD854x family is specified for single or dual power supplies of +2.2V to +5.5V.

The AD8541ARZ-REEL7 is available in 5-lead SOT-353 and SOT-23, and 8-lead SOP (COIC-8) packages.

The AD8542ARZ-REEL7 is available in 8-lead MSOPand SOP packages. The AD8544ARZ-REEL7 is available in 14-lead SOP packages.

## **FEATURES**

- Low Offset Voltage: 3.0 mV Maximum
- Gain-Bandwidth Product: 1.2MHz
- High Slew Rate: 1.0 V/µs
- Low Power: 85 µA per Amplifier Supply Current
- Unity Gain Stable
- Rail-to-Rail Input and Output
- Input Voltage Range: -0.2 to +5.2 V at 5V Supply
- Operating Power Supply: +2.2 to +5.5 V
- Operating Temperature Range: -40°C to +125°C
- ESD Rating: HBM 4kV, CDM 2kV

## **APPLICATIONS**

- Smoke/Gas/Environment Sensors
- Audio Outputs
- Active Filters
- ASIC Input or Output Amplifier
- Sensor Interfaces
- Portable Equipment
- Battery-Powered Instrumentation

## **PIN CONFIGURATION**

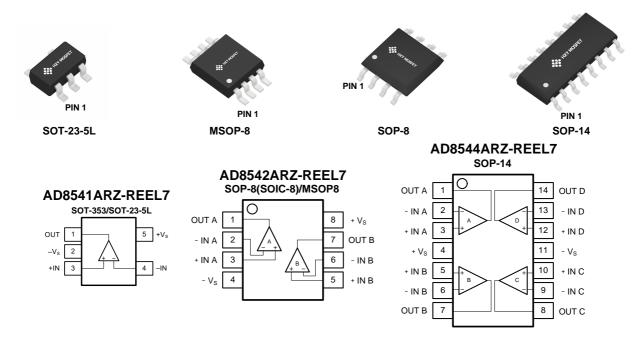


Figure 1. Pin Assignment Diagram



#### **ABSOLUTE MAXIMUM RATINGS**

Supply Voltage, +V <sub>S</sub> to -V <sub>S</sub>	7V
Input Common Mode Voltage Range	
(-V <sub>S</sub> )	$-0.5V$ to $(+V_S) + 0.5V$
Storage Temperature Range	65°C to +150°C
Junction Temperature	+160°C
Lead Temperature (Soldering 10sec)	+260°C
ESD Susceptibility	
HBM	4000V
MM	400V
CDM	2000V

## RECOMMENDED OPERATING CONDITIONS

Operating Temperature Range .....-40°C to +125°C

Note: Stress greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device.

This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification are not implied.

Exposure to absolute maximum rating conditions for extended periods may affect reliability.

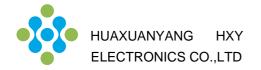
## **OEDEROMG OMFORMATION**

Type Number	Package Name	Package Quantity
AD8541ARTZ	SOT-23-5L	3000
AD8541AKSZ	SOT-353	3000
AD8542ARZ	SOP-8L	2500
AD8542ARMZ	MSOP-8L	3000
AD8544ARZ	SOP-14L	2500

## **ELECTRICAL CHARACTERISTICS**

Vs = 5.0V,  $TA = +25^{\circ}C$ , VcM = Vs / 2, Vo = Vs / 2, and  $RL = 10k\Omega$  connected to Vs / 2, unless other wise noted. Boldface limits apply over the specified temperature range, TA = -40 to  $+ 125^{\circ}C$ .

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Vos	Input offset voltage			±1.0	±3.0	mV
VosTc	Offset voltage drift	T <sub>A</sub> = <b>-</b> 40 to +125 °C		±1	3.5	μV/°C
PSRR	Power supply	Vs= 2.2 to 5.5 V, VcM< Vs+-2V	80	110		- dB
1 OKK	rejection ratio	T <sub>A</sub> = <b>-</b> 40 to +125 °C	75			ub ub
				5	50	
Ів	Input bias current	T <sub>A</sub> = +85 °C			200	pА
		T <sub>A</sub> = +125 °C			2000	
los	Input offset current			10	50	pА
Vn	Input voltage noise	f = 0.1 to 10 Hz		6		μV <sub>P-P</sub>
<b>e</b> n	Input voltage noise f = 10 kHz	f = 10 kHz		27		nV/√Hz
den	density	f = 1 kHz		30		110/0 円2
In	Input current noise density	f = 1 kHz		5		fA/√Hz



# **ELECTRICAL CHARACTERISTICS**

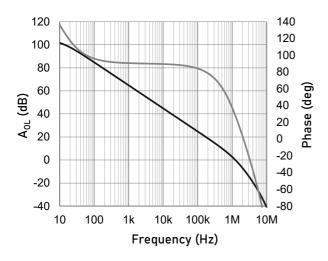
 $Vs = 5.0V, T_A = +25 ^{\circ}C, \ V_{CM} = Vs \ / \ 2, \ Vo = Vs \ / \ 2, \ and \ R_L = 10 k\Omega \ connected \ to \ Vs \ / \ 2, \ unless \ other \ wise \ noted.$  Boldface limits apply over the specified temperature range,  $T_A = -40 \ to \ + \ 125 ^{\circ}C.$ 

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
Vсм	Common-mode voltage range		Vs0.1		Vs++0.1	V	
		Vs= 5.5 V,Vcм= <b>−</b> 0.1 to 5.6 V	70	83			
	Common-mode	VcM= 0 to 5.3 V, TA= -40 to +125 °C	65				
CMRR	rejection ratio	Vs= 2.2 V,VcM= <b>-</b> 0.1 to 2.2 V	65	77		dB	
	V <sub>CM</sub> = 0 to 2.2 V,T <sub>A</sub> = -40 to +125 °C	60					
0	lanut annaitana	Differential		2.0			
Cin	Input capacitance	Common mode		3.5		pF	
		$R_L = 25 \text{ k}\Omega$ , $V_O = 0.05 \text{ to } 3.5 \text{ V}$	90	105			
^	Open-loop voltage	T <sub>A</sub> = -40 to +125 °C	85			-10	
Avol	gain	$R_L = 2 k\Omega$ , $V_O = 0.15 \text{ to } 3.5 \text{ V}$	85	100		dB	
		T <sub>A</sub> = -40 to +125 °C	80				
GBW	Gainbandwidth product			1.2		MHz	
SR	Slew rate	G = +1, CL= 100 pF, Vo= 1.5 to 3.5	V	1.0		V/µs	
THD+N	Total harmonic distortion + noise	G = +1, f = 1 kHz, Vo = 1 V <sub>RMS</sub>		0.003		%	
		To 0.1%, G = +1, 1V step		1.5			
ts	Settling time	To 0.01%, G = +1, 1V step		1.8		μs	
tor	Overload recovery time	To 0.1%, V <sub>IN</sub> * Gain > Vs		2.5		μs	
Vон	High output voltage	RL= 50 kΩ	Vs+-6	Vs+-3		mV	
VOH	swing	R <sub>L</sub> = 2 kΩ	Vs+-100	Vs+-65		1111	
Vol	Low output voltage	R <sub>L</sub> = 50 kΩ		Vs-+2	Vs-+4	m\/	
VOL	swing	$R_L=2 k\Omega$		Vs-+43	Vs-+65	mV	
loo	Short-circuit current	Source current through 10Ω		40		m ^	
Isc	Short-circuit current	Sink current through 10Ω		50		mA mA	
Vs	Operating supply voltage		2.2		5.5	V	
la.	Quiescent current			85	120		
	(per amplifier)	T <sub>A</sub> = <b>-</b> 40 to +125 °C			150	μА	
Та	Operating temperature range		-40		+125	°C	



## TYPICAL PERFORMANCE CHARACTERISTICS

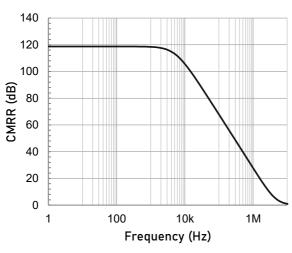
At  $T_A$  = +25°C,  $V_{CM}$  =  $V_S/2$ , and  $R_L$  = 10k $\Omega$  connected to  $V_S/2$ , unless otherwise noted.

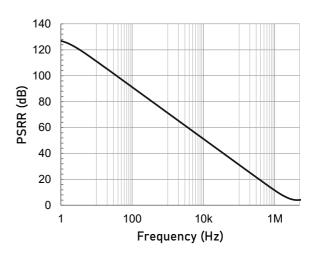


1,000 (ZH)/\100 lose Noise Noise Noise Noise Noise Noise Noise 10 lose 10 lose

Open-loop Gain and Phase as a function of Frequency.

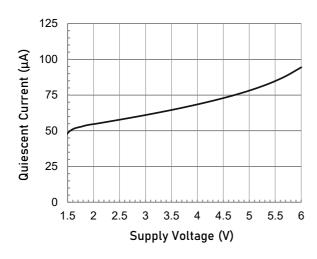
Input Voltage Noise Spectral Density as a function of Frequency.

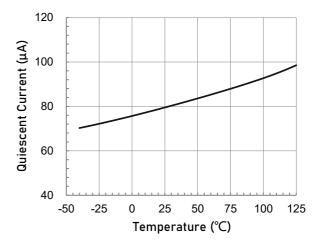




Common-mode Rejection Ratio as a function of Frequency.

Power Supply Rejection Ratio as a function of Frequency.



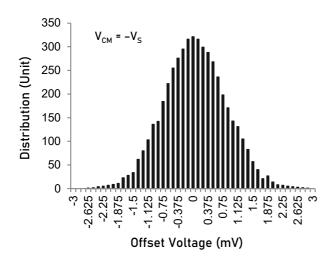


Quiescent Current as a function of Supply Voltage.

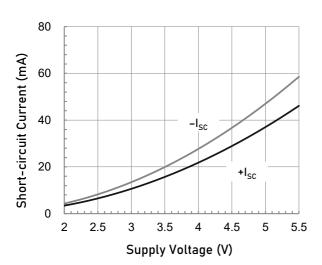
Quiescent Current as a function of Temperature.

## TYPICAL PERFORMANCE CHARACTERISTICS

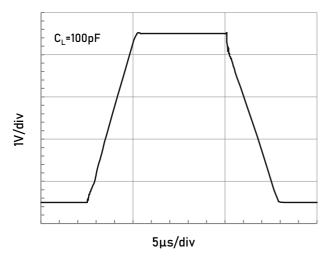
At  $T_A$  = +25°C,  $V_{CM}$  =  $V_S/2$ , and  $R_L$  = 10k $\Omega$  connected to  $V_S/2$ , unless otherwise noted.



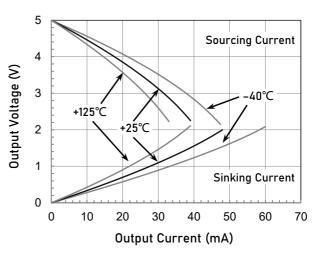
Offset Voltage Production Distribution



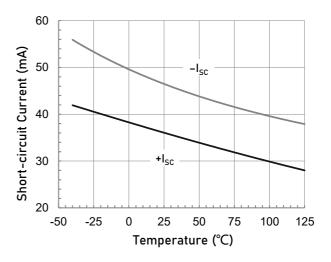
Short-circuit Current as a function of Supply Voltage.



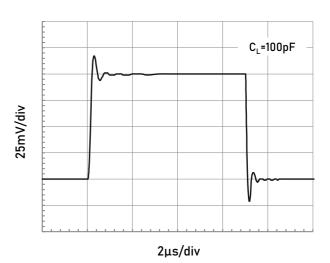
Large Signal Step Response.



Output Voltage Swing as a function of Output Current.



Short-circuit Current as a function of Temperature.



Small Signal Step Response.



## APPLICATION NOTE

Size

AD854xARZ-REEL7 family series op amps are unity-gain stable and suitable for a wide range of general-purpose applications.

Thesmall footprints of the AD854xARZ-REEL7 family packages save space on printed circuit boards and enable the design of smaller electronic products.

Power Supply Bypassing and Board Layout

AD854xARZ-REEL7 family series operates from a single 2.2V to 5.5V supply or dual ±1.0V to ±3V supplies. For best performance, a 0.1µF ceramic capacitor should be placed close to the V<sub>DD</sub> pin in single supply operation. For dual supply operation, both  $V_{DD}$  and  $V_{SS}$  supplies should be bypassed to ground with separate 0.1 $\mu$ F ceramic capacitors.

#### Low Supply Current

The low supply current (typical 85µA per channel) of AD854xARZ-REEL7 family will help to maximize battery life. They are ideal forbattery powered systems.

#### Operating Voltage

AD854xARZ-REEL7 family operates under wide input supply voltage (2.2V to5.5V)In addition, all temperature specificationapply from -40°C to +125°C. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-Ion battery lifetime.

#### Rail-to-Rail Input

The input common-mode range of AD854xARZ-REEL7 family extends 100mV beyond the supply rails (Vss-0.1V to V<sub>DD</sub>+0.1V). This is achieved by using complementary input stage. For normal operation, inputs should be limited to this range.

#### Rail-to-Rail Output

Rail-to-Rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating in low supply voltages. The output voltage of AD854xARZ-REEL7 family can typically swing to less than 10mV from supply rail in light resistive loads (>100k $\Omega$ ), and 60mV of supply rail in moderate resistive loads (10k $\Omega$ ).

#### Capacitive Load Tolerance

The AD854xARZ-REEL7 family is optimized for bandwidth and speed, not for driving capacitive loads. Output capacitance will create a pole in the amplifier's feedback path, leading to excessive peaking and potential oscillation. If dealing with load capacitance is a requirement of the application, the two strategies to consider are (1) using a small resistor in series with the amplifier's output and the load capacitance and (2) reducing the bandwidth of the amplifier's feedback loop by increasing the overall noise gain. Figure 2 shows a unity gain follower using the series resistor strategy. The resistor is olates the output from the capacitance and, more importantly, creates a zero in the feedback path that compensates for the pole created by the output capacitance.

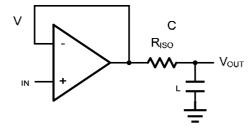


Figure 2 Indirectly Driving a Capacitive Load Using Isolation Resistor



The bigger the  $R_{ISO}$  resistor value, the more stable  $V_{OUT}$  will be. However, if there is a resistive load  $R_L$  in parallel with the capacitive load, a voltage divider (proportional to  $R_{ISO}/R_L$ ) is formed, this will result in a gain error.

The circuit in Figure 3 is an improvement to the one in Figure 2.  $R_F$  provides the DC accuracy by feed-forward the  $V_{IN}$  to  $R_L$ .  $C_F$  and  $R_{ISO}$  serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving the phase margin in the overall feedback loop. Capacitive drive can be increased by increasing the value of  $C_F$ . This in turn will slow down the pulse response.

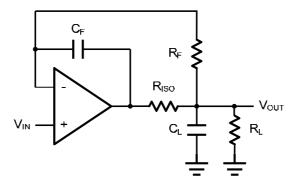


Figure 3. Indirectly Driving a Capacitive Load with DC Accuracy

## INSTRUMENTATION AMPLIFIER

The triple AD854xARZ-REEL7 family can be used to build a three-op-amp instrumentation amplifier as shown in Figure 4. The amplifier in Figure 4 is a high input impedance differential amplifier with gain of  $R_2/R_1$ . The two differential voltage followers assure the high input impedance of the amplifier.

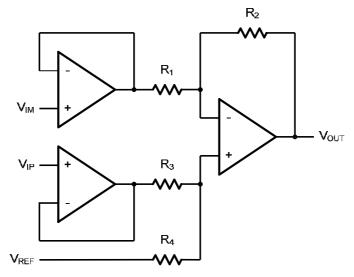


Figure 4. Instrument Amplifier

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# TYYPICAL APPLICATION CIRCUITS

### Differential amplifier

The differential amplifier allows the subtraction of two input voltages or cancellation of a signal common the two inputs.

It is useful as a computational amplifier in making a differential to single-end conversion or in rejecting a common mode signal. Figure 5. shown the differential amplifier using AD854xARZ-REEL7 family.

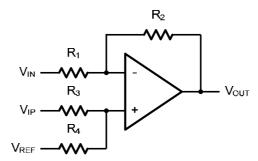


Figure 5. Differential Amplifier

$$V_{\text{OUT}} = \left(\frac{R_1 + R_2}{R_2 + R_4}\right) \frac{R_4}{R_1} V_{\text{IN}}^2 - V_{\text{IR}1}^R + \left(\frac{R_1 + R_2}{R_2 + R_4}\right) \frac{R_2}{R_1} V_{\text{REF}}$$

If the resistor ratios are equal (i.e.  $R_1=R_3$  and  $R_2=R_4$ ), then

$$V_{\text{OUT}} = \frac{R_2}{R_1} (V_{\text{IP}} - V_{\text{IN}}) + V_{\text{REF}}$$

#### Low Pass Active Filter

The low pass active filter is shown in Figure 6. The DC gain is defined by  $-R_2/R_1$ . The filter has a -20dB/decade roll-off after its corner frequency  $f_C=1/(2\pi R_3C_1)$ .

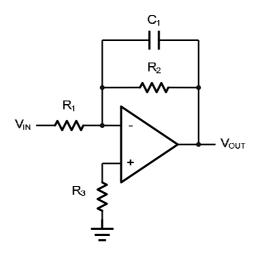
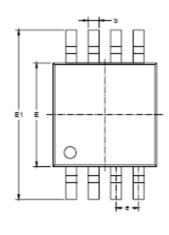


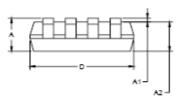
Figure 6. Low Pass Active Filter



# PACKAGE OUTLINE DIMENSIONS MSOP-8

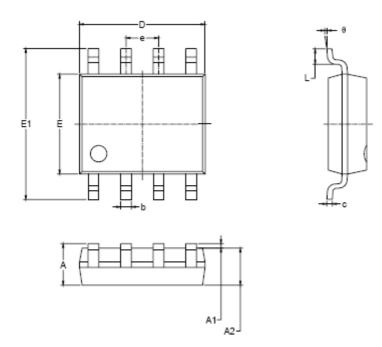






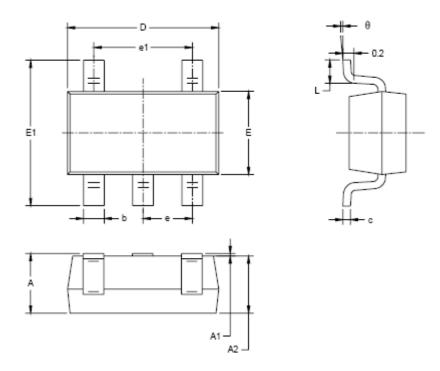
Symbol	Dimen In Milli		nsions nches	
-	MIN	MAX	MIN	MAX
Α	0.820	1.100	0.032	0.043
A1	0.020	0.150	0.001	0.006
A2	0.750	0.750 0.950 0.030		0.037
b	0.250	0.380	0.010	0.015
С	0.090	0.230	0.004	0.009
D	2.900	3.100	0.114	0.122
E	2.900	3.100	0.114	0.122
E1	4.750	5.050	0.187 0.19	
e	0.650	BSC	0.026	BSC
L	0.400	0.800	0.016	0.031
θ	0°	6°	0°	6°

# SOP-8(SOIC-8)



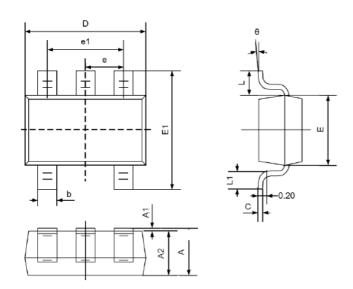
Symbol	l .	Dimensions In Millimeters		isions ches
7	MIN	MAX	MIN	MAX
Α	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
С	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.27 BSC		0.050	BSC
L	0.400	1.270	0.016	0.050
9	0°	8°	0°	8°

## **SOT-23-5L**



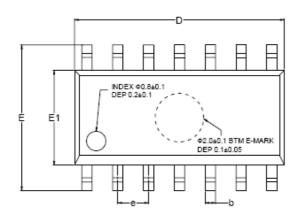
			Dimensions In Inches	
MIN	MAX	MIN	MAX	
1.050	1.250	0.041	0.049	
0.000	0.100	0.000	0.004	
1.050	1.150	0.041	0.045	
0.300	0.500	0.012	0.020	
0.100	0.200	0.004	0.008	
2.820	3.020	0.111	0.119	
1.500	1.700	0.059 0.00		
2.650	2.950	0.104	0.116	
0.950	BSC	0.037	BSC	
1.900 BSC		0.075	BSC	
0.300	0.600	0.012	0.024	
0°	8°	0°	8°	
	In Mill MIN 1.050 0.000 1.050 0.300 0.100 2.820 1.500 2.650 0.950 1.900 0.300	1.050 1.250 0.000 0.100 1.050 1.150 0.300 0.500 0.100 0.200 2.820 3.020 1.500 1.700 2.850 2.950 0.950 BSC 1.900 BSC 0.300 0.800	In Millimeters	

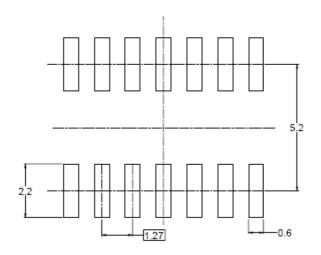
## **SOT-353**



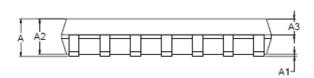
	Dimens	sions	Dimensions		
Symbol	In Millimeters		In Inches		
	Min	Max	Min	Max	
Α	0.900	1.100	0.035	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.000	0.035	0.039	
b	0.150 0.350		0.006	0.014	
С	0.080 0.150		0.003	0.006	
D	2.000 2.200		0.079	0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
е	0.650T	ΥP	0.026T	ΥP	
e1	1.200	1.400	0.047	0.055	
L	0.525R	EF	0.021REF		
L1	0.260	0.460	0.010	0.018	
θ	0° 8°		0°	8°	

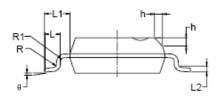
## **SOP-14**





RECOMMENDED LAND PATTERN (Unit: mm)





Symbol	Dimens	sions In Mill	imeters	Dime	nsions In Ir	nches
Symbol	MIN	MOD	MAX	MIN	MOD	MAX
Α	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.004		0.010
A2	1.25		1.65	0.049		0.065
A3	0.55		0.75	0.022		0.030
b	0.36		0.49	0.014		0.019
D	8.53		8.73	0.336		0.344
E	5.80		6.20	0.228		0.244
E1	3.80		4.00	0.150		0.157
е		1.27 BSC			0.050 BSC	
L	0.45		0.80	0.018		0.032
L1		1.04 REF			0.040 REF	
L2		0.25 BSC		0.01 BSC		
R	0.07			0.003		
R1	0.07			0.003		
h	0.30		0.50	0.012		0.020
θ	0°		8°	0°		8°

# AD854xARZ-REEL7 1MHz General Purpose,RRIO CMOS Amplifers

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